



THIN FILM DEPOSITION SYSTEMS

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Elettrorava Company Profile

We design, develop, and manufacture Thin Films process equipment solutions for R&D, pilot and production applications. Our products include a complete array of turnkey solution, our competency help to develop also tailor made solutions based on our customers needs.

People are our recipe



HIGH SPECIALIZED ENGINEERING

Engineering process is maintained in house in all phases. Our customers need equipment that obtains high purity, conformal, dense and uniform coatings. To achieve this all engineering processes are monitored step by step, **from conception to commissioning**.



THIN FILM PROCESS KNOW-HOW

Thanks to our 35 years experience in thin film processes we support our client through all stages of development, testing and validation of the deposition processes. All machines supplied to our customers are accompanied by a process guarantee.



Our Vision

Tomorrow will be a place where new technologies need a vertical integration of design, manufacturing, and process optimization. New materials and electronics will change people's life, and we will be part of this change.

#nanotec is the keyword!







Our History

Driving innovation since 1922







Our Value Proposition

More Value Less Complexity



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Worldwide Customers

Italian technology, international breath





Our References

Customers Satisfied Over the World







Market Served

Thin Film Application in Different Markets



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Markets Solar Photovoltaics

High efficiency and special applications



Requirements

- High efficiency solar cells
- Large area solar cells
- Low weight, low cost per Watt produced

Applications

- Amorphous silicon solar cells with p-i-n structure
- Amorphous silicon alloys (SiC, SiGe) solar cells with tandem structure (2 x p-i-n)
- Heterojunction solar cells combining thin film silicon with polycristalline or crystalline Si wafers

Technologies

- Plasma Enhanced Chemical Vapor Deposition for semiconductor thin layers
- Sputtering for deposition of Transparent Conductive Oxides as solar cell top and bottom contacts

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Markets Optical Coatings

High reflectivity, uniformity and density thin films



Requirements

- Extremely low absorption highly transparent materials
- High density materials with high laser damage threshold
- Very good uniformity over large surfaces
- Stoichiometric oxide materials
- Excellent adhesion

Applications

- High reflectivity (>99.98%) dielectric multilayer mirrors at designed wavelengths (e.g. 633nm)
- Low absorption filters in a wide range of optical designs
- Optical devices with high laser damage threshold

• Dual Ion Beam Sputtering using one Sputtering Ion Beam Source and one Assist Ion beam

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• Electron Beam Evaporation with assistance from one Ion Beam Source



Markets Optoelectronics and Semiconductors

High efficiency systems, wide range of deposited materials



Requirements

- Highly photoemissive materials
- High carrier lifetime materials
- Metals for contacts
- Transparent Conductive Oxides

Applications

- Light Emitting Devices
- Thin Film Transistors for Large area Displays
- Small size Integrated Circuits

Technologies

- PECVD
- Magnetron Sputtering
- PVD electron beam evaporation





Markets Aeronautics and Aerospace

Quality solutions for a complex market



Requirements

- Reliability
- Repeatability
- Quality
- Endurance performances
- Work in extreme environment

Applications

- Engine components
- Cockpit and Fuselage components
- Navigation systems
- Avionics

Technologies

- CVD
- PECVD
- Sputtering
- PVD





Markets Medical

High performance and biocompatibility materials



Requirements

- Reliability
- Repeatability
- Quality
- Endurance performances
- Biocompatibility

Applications

- Orthopedic Implants
- Cardiovascular Devices
- Neurosurgical Devices
- Surgical Instruments
- In Vitro Diagnostic

Technologies

- PVD
- Sputtering
- Ion implantation

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Our Scientific Committee

R&D to meet tomorrow's challenges

Our scientific committee is the point of reference for our R&D projects, the resolution of complex problems and the validation of new processes. They represent our competencies at the service of our clients' challenges.



Paolo Rava Ph.D. @ MIT R&D Director @ Elettrorava

He carried out research activities on the electrical and optical properties of crystalline semiconductors (silicon, gallium arsenide and indium phosphide)

and on the conversion efficiency of photovoltaic solar cells.



Pietro Mandracci Ph.D. @ Trento University Professor @ Politecnico di Torino

His main research interests deal with the study of the plasma-assisted modification of surfaces and the growth of thin-films and nanostructures. He is also involved in new applications of nanotechnology to biology, biomedicine, and to the energy savings/production industrial fields.



Ruud E.I. Schropp Ph.D. @ University of Groningen Professor @ University of Western Cape He authored more than 600 papers and 12 patents Currently, his research

12 patents. Currently, his research interests are c-Si heterojunctions, next generation thin (nanostructured) films for photovoltaics, enhanced light coupling by plasmonics, nanophotonics, and photon conversion, and hybrid tandem solar cells.



Caterina Summonte MSc in Physics @ University of Bologna Researcher @ IMM CNR

She has been responsible for her institution in two European research projects. She authored about 120 articles in international Journals. Her main interest is the optical characterization of thin film and nanostructured materials.





Our CVD Technologies

Production and R&D Systems Solutions

PECVD

Plasma Enhanced Chemical Vapor Deposition (RF, VHF, MW)

ICP - PECVD

Inductive Coupled Plasma PECVD

ECR - PECVD Electron

Cyclotron Resonance PECVD

ALD Atomic Layer Deposition



MOCVD

Metal Organic Chemical Vapor Deposition

> HWCVD Hot Wire Chemical Vapor Deposition

HTCVD

High Temperature Chemical Vapor Deposition



Our PVD Technologies

Production and R&D Systems Solutions



MULTI SPUTTERING

Multi Magnetron Sputtering Deposition

LASER SPUTTERING Laser Sputtering Deposition

EBD Electron Beam Deposition

4/16/2020

DIBSD

Dual lon

Beam

Sputtering

Deposition

TE Thermal Evaporation







Our Products

High reliable and top selling quality systems





THIN FILM DEPOSITION STANDARD SYSTEMS

We supply a complete array of machines for Thin Films Deposition testing and production. Our products portfolio includes both PVD and CVD solutions from Sputtering, Ion Beam, Electron Beam to Plasma Enhanced CVD through Evaporation systems.

TAILOR MADE SYSTEMS

Although having a line of standard systems, we pay special attention to specific customer needs, offering complete tailor made systems designed to achieve the performance required by the customer and provided with a process guarantee.

MULTI PROCESS, MULTI CHAMBER SYSTEMS

In order to satisfy the need to obtain products through deposition with different technologies, we are able to design and build multi-process machines able to operate automatically both in sequential and single mode.

TURBOMOLECULAR PUMPS AND VACUUM UNITS

We produce turbomolecular pumps in a wide range of pumping speed that may be supplied both as stand alone components and as part of complete pumping units including primary pumps, valves, gauges, etc.





Products Thin Film Standard Systems

Three product lines to meet customer's needs

We have a range of standard machines capable of meeting all the most stringent requirements of our customers. Our equipment utilizes the best vacuum and electronic components for long-term reliable operation with minimal maintenance.



PVD Series

- UHV capability (10⁻⁹mbar) or HV capability (10⁻⁸mbar)
- Substrate size from 5 cm up to 30 cm
- Process temperature: from room temperature up to 600°C
- Deposition sources (stand alone or in combination):
 - Single crucible or multi-crucible electron beam source (6,10 and 15 KW)
- Thermal evaporation Joule effect sources
- Heated substrate rotation at variable speed
- Turbomolecular / cryogenic / TSP pumping
- Quartz Crystal Thickness Controller
- Optical Thickness Monitor

S Series

- UHV capability (10^{-9} mbar) or HV capability (10^{-8} mbar)
- Substrate size from 5 cm up to 30 cm
- Process temperature: from room temperature up to 600°C
- Deposition sources (stand alone or in combination):
 - Magnetron sputtering cathodes
- Ion beam sources for sputtering, assisting and substrate etching
- Heated and tilted substrate rotation at variable speed
- Turbomolecular / cryogenic / TSP pumping
- Quartz Crystal Thickness Controller
- Optical Thickness Monitor

CVD Series

- UHV capability (10-9 mbar) or HV capability (10-8 mbar)
- Direct or remote plasma excitation by RF, VHF, MW or ECR
- Dedicated or additional Hot Wire CVD
- Substrate size from 10 cm x 10 cm up to 32 cm x 35 cm
- Process temperature: standard up to 400°C, optional up to 1000°C
- Modular process gas manifold with mass flow controllers
- Automatic process pressure control by throttle valve and capacitance manometer
- Turbomolecular pumping for ultimate vacuum and during process
- Deposited material quality and homogeneity guarantees





Products Multi Process Systems

Configured by customers



Main Features

- Several process chambers (up to seven) based on one or more techniques (PECVD, HWCVD, Sputtering, etc.)
- Transfer of substrate under high vacuum from one process chamber to another in any sequence
- Load Lock chamber for substrate loading under vacuum, with automatic multi substrate feeder cassette
- Separate pumping units and gas manifolds for each process chamber to avoid cross contamination

Applications

- Applications: thin film multilayer devices based on a-Si:H, μc-Si_xC_γ:H, a-Si_xC_γ:H, a-Si_xN_γ:H, μc-Si_xN_γ:H (solar cells, sensors, LED's, TFT's etc.)
- Substrate size from 10 cm x 10 cm up to 35 cm x 32 cm

Process Guarantees

• Process guarantees for optimum specific device properties (semiconductor materials and electronic devices, metals, optical materials, etc.) can be offered









Products Turbomolecular Pumps

From 1975 high quality vacuum components

High pumping speed combined with relatively low rotation speed give our turbomolecular pumps high efficiency and operability, reducing the risk of breakage. All models can also be produced in corrosion resistant version.

The pumps are controlled by ETC series electronic control unit, that can be configured with RS-232, RS-485 or ProfibusDP connection.

MODEL		ETP 300	ETP 450	ETP 1000	ETP 6000
Pumping Speed N_2	(l/s)	330	460	1000	5500
Pumping Speed $\rm H_{e}$	(I/s)	340	520	1150	6000
Pumping Speed H_2	(l/s)	300	480	1100	5000
Ultimate pressure	(mbar)	5 x 10 ⁻¹⁰			
Rotational Speed	(rpm)	42000	36000	36000	14000
Inlet Flange		DN160ISO DN160CF	DN160ISO DN160CF	DN200ISO DN200CF	DN500ISO
Lubrication Type		Grease	Grease	Grease	Oil
Operating Position		Any	Any	Vertical up or down	Vertical up





Our Services

Customer Centered Solutions

INTERNAL APPLICATION LABORATORY

Our staff are trained to identify all key aspects of new process study and validation. Our engineers can help to optimize the system performance whether you are developing a new deposition process, or re-engineering an existing one.

CUSTOMER SUPPORT

Our customer support department take care of all our systems from commissioning to end of life, ensuring constant and continuous operation. We offer ready on stock spare parts with fast delivery, staff training and technical operation all over the world.

RETROFIT AND TECHNICAL SERVICIES

Our technical knowledge also enables us to operate on existing systems by engineering their technological upgrade and adapting them to the process required by the customer.

COLLABORATION AND R&D

We offer collaboration for national and international research projects with University or other private companies, participating to European fund raising.







Services Our Laboratory Facilities

Internal R&D capability

Our laboratory is equipped with systems that cover the major technologies and is used by our technicians for research projects, customer servicing and validation of new processes.



PECVD

- Deposition area up to 1 x 1,3 mt
- Substrate height up to 5 mm
- Gas type: SiH4, H2, CH4, PH3, B2H6, N2O
- Temperature: 100-400 °C

SPUTTERING

- Deposition area up to 50 x 50 cm
- Substrate height up to 5 mm
- Gas type: Ar, O2
- Temperature: 100-300 °C

THERMAL EVAPORATION

- Deposition area up to multiple substrates 15cm x 15cm
- Substrate height up to 5 cm

ELECTRON BEAM

- Deposition area up to multiple substrates 15 x 15 cm or 200 mm diameter
- Substrate height up to 5 mm
- Gas type: Ar, O2
- Temperature: 100-300 °C





Services Co-R&D

Enabling Innovations



R&D for innovation

We believe in innovation, through continuous research and development projects carried out with our partners. As technologies advance, challenges lead us to solve increasingly complex problems that can be tackled through experience and an open innovation approach.

In past years we carried out more than ten research project with our customers and partners.

Partnership

Over the years we have built a network of partners of primary importance and specialized in scientific research in the field of thin film deposition. This network includes leading Italian and European universities and institutional research centers.

More value

Thanks to our R&D service we add value to our customers' solutions, supporting them during the initial process testing, certification and optimization during the entire machine production life.

Xox > elettrorava





Our Competencies at your Service

We have the expertise to guarantee the results required by our customers, both in the field of production and scientific research. Before our systems leave the factory they have been tested and validated and are delivered with a guarantee of the process for which they were built.





Competence and quality for our solutions

How to win the market leadership







Showcase 1 Multi-Process, Multi-Chamber

Different Processes – One Solution

Multi-chamber system with one load-lock chamber for substrate holding, one transfer chamber with cluster tool robot for substrate transfer. Three to Seven Deposition Process Chambers based on RF-PECVD, ICP-PECVD, ECR-PECVD, RIE, Sputtering.

MULTIPLE WAFERS

Automatic wafer feeder with Upward or Downward deposition of thin films.

PURITY GUARANTEE

Turbomolecular pumping for ultimate vacuum and dry pumping for clean process



HIGH THROUGHTPUT

Gas Cabinet with multiple panels with up to 50 MFCs and independent operations for each chamber (pumps, MFCs, RF generators)

FULLY AUTOMATED

Complete automation control with recipe and real time operation

XoX > elettrorava ...





Showcase 2 Dual Ion Beam Sputtering

High quality and flexibility equipment for optical coatings

The basic DIBS (Dual Ion Beam Sputtering) system has two independent ion sources, one ion source for sputtering (IBS) the material from the target and another ion source for pre-cleaning of the substrate and ion-assisted deposition (IAD). The assist/etch source can fulfil various functions: it can be used to etch the substrate; it can provide "assistance" to the deposition process by bombarding the depositing film with energetic ions which can improve or modify the film properties or stoichiometry by physical and/or chemical effects; it can also be used as a low-energy pre-clean of the substrate prior to deposition.

DEPOSITED MATERIALS

Oxides: AI2O3, Ta2O5, SiO2 and TiO2 Nitrides: Si3N4, etc. Other: MgF2, LaF3, Nb2O5, ZrO3, Y2O3, HfO2, YF3 etc.

OPTIMIZED TARGET EXPOSURE

Rotating target for a better etch result with an automatic variable position and incidence by rotation. Plus a continuous automatic oscillation of angle while depositing.



FILM THICKNESS

Planetary substrate holder with automatic rotation function during deposition.

BEAM CONTROL

The beam is controlled by a three grid system that helps beam collimation, suppresses electron back-streaming and reduce redeposition of sputtered material back inside the source.





Showcase 3 Electron Beam Deposition

Multiple crucibles electron beam evaporation systems

Electron beam deposition systems can be stand alone or assisted by ion beam for optical coatings. In this application the electron beam is the main deposition source and the ion beam source is used both for preclean and assist during deposition process. This combination, including the possibility of high vacuum in the chamber, allows a uniform deposition with a guarantee of high purity and absence of inclusions between layers. This technology is used for optical coatings in industrial, aerospace and military applications.

CONFIGURABLE SOURCES

Single or Dual Electron Beam source, assisted by an Ion Beam Source for assist and preclean.

Optionally Thermal Sources and Magnetron Sputtering Cathodes.

MULTIPLE MATERIAL EVAPORATION

Crucible indexer for selection and deposition of multiple materials



FILM THICKNESS

Planetary substrate holder with automatic rotation function during deposition.

DEPOSITION CONTROL

The deposition rate from the electron beam source is controlled by the Quartz Crystal Thickness Controller with a PID loop on the emission current of the beam







Showcase 4 PECVD

Plasma Enhanced Chemical Vapor Deposition Multi-chamber systems for large substrates size

A modular multi-chamber PECVD system for deposition on substrates with size from 10cm x 10cm up to 35 x 32 cm, separate Load Lock with pre heating with thermal radiation lamps, automatic robot for substrate handling between process chambers. The system is designed to prevent incorporation of residual impurities and cross contamination between different layers. The possible applications are R&D and small production of flexible OLED display, photovoltaics cells, LEDS, semiconductors and more.

CONFIGURABLE HEIGHT

Configurable electrode height from 15 to 50 mm to the substrate holder in each chamber

WIDE MATERIALS RANGE

Wide range of deposited materials as follows:

- Intrinsic and doped a-Si:H
- Intrinsic and doped µ-Si:H
- Silicon alloys such as SixCy:H, SixNy:H, SixOy:H



FILM UNIFORMITY

The design of the electrode and the purity allowed by the HV system guarantee state of the art deposited layers with a thickness standard deviation uniformity $< \pm 2,5 \%$

FLEXIBLE WORK FLOW

Each chamber can work independently or in a batch recipe for multilayer depositions



Contact us

